

NWP2081T

Half-bridge driver IC

Rev. 1 — 3 September 2013

Product data sheet

1. General description

The NWP2081T is a high-voltage monolithic integrated circuit made using the latch-up free Silicon-On-Insulator (SOI) process. The circuit is designed for driving MOSFETs in a half-bridge configuration.

2. Features and benefits

- Latch-up free and robust half-bridge driver
- Output driver capability: $I_{O(sink)} = 400 \text{ mA}$ and $I_{O(source)} = 200 \text{ mA}$
- Maximum frequency 800 kHz
- Outputs in phase with CLK input
- Adjustable dead-time
- Low active shutdown input

3. Applications

- Driver (via external MOSFETs) for any kind of load in a half-bridge configuration

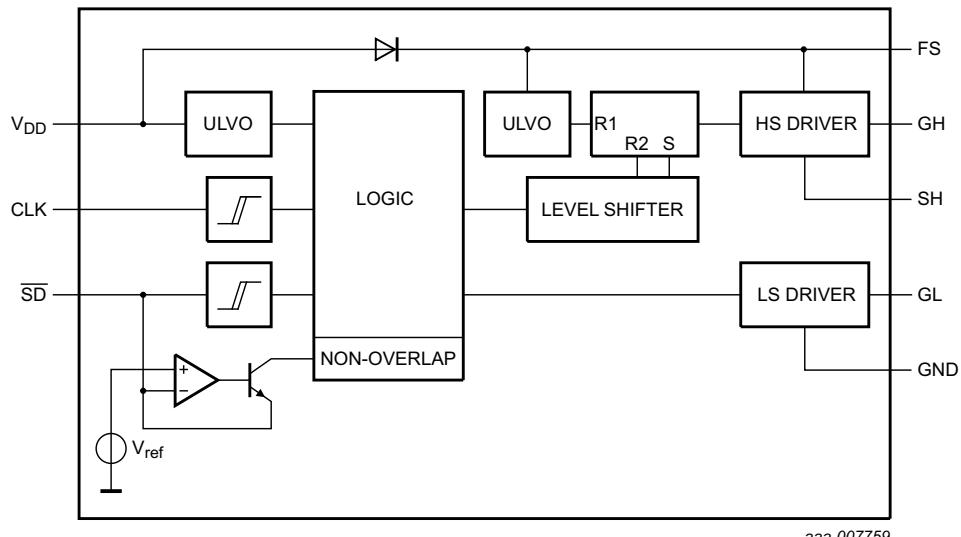
4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Name	Description		
NWP2081T	SO8	plastic small outline package; 8 leads		SOT96-1



5. Block diagram



aaa-007759

Fig 1. NWP2081T block diagram

Refer to [Figure 4](#) for detailed information on the required application components.

6. Pinning information

6.1 Pinning

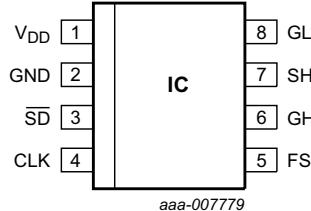


Fig 2. NWP2081T pinning diagram

6.2 Pin description

Table 2. Pin description NWP2081T

Symbol	NWP2081T (SO8)	Description
V _{DD}	1	IC supply
GND	2	IC ground and low-side driver return
SD	3	low active analog shutdown input and non-overlap time setting
CLK	4	clock logic input
FS	5	floating supply voltage

Table 2. Pin description NWP2081T ...*continued*

Symbol	NWP2081T (SO8)	Description
GH	6	high-side MOSFET gate
SH	7	high-side MOSFET source
GL	8	low-side MOSFET gate

7. Functional description

7.1 Start-up state

The IC enters the start-up state when the supply voltage on pin V_{DD} increases. In the start-up state, the high-side power transistor is non-conducting and the low-side power transistor is switched on. The internal circuit is reset and the capacitor on the bootstrap pin FS is charged. The start-up state is defined until the value of $V_{DD} = V_{DD(\text{start})}$. After which the IC switches to the oscillation state.

The circuit enters the start-up state again when the voltage on pin $V_{DD} < V_{DD(\text{stop})}$.

7.2 NWP2081T oscillation state

In the oscillation state, the output voltage of the GL and GH drivers depend on the logical signals CLK and \overline{SD} (see [Table 3](#)).

Table 3. NWP2081T logic table

State	CLK	SD	GH	GL
start-up	-	-	LOW	HIGH
oscillation	0	1	LOW	HIGH
oscillation	1	1	HIGH	LOW
oscillation	0	0	LOW	LOW
oscillation	1	0	LOW	LOW

7.3 NWP2081T non-overlap time

The external resistor (R_{SD}) on pin \overline{SD} sets the non-overlap time of the NWP2081T. The relationship between this resistor value and actual dead-time is listed in [Figure 3](#).

It is essential to add a 10 nF to 100 nF decoupling capacitor across R_{SD} to ensure a noise immune dead-time system.

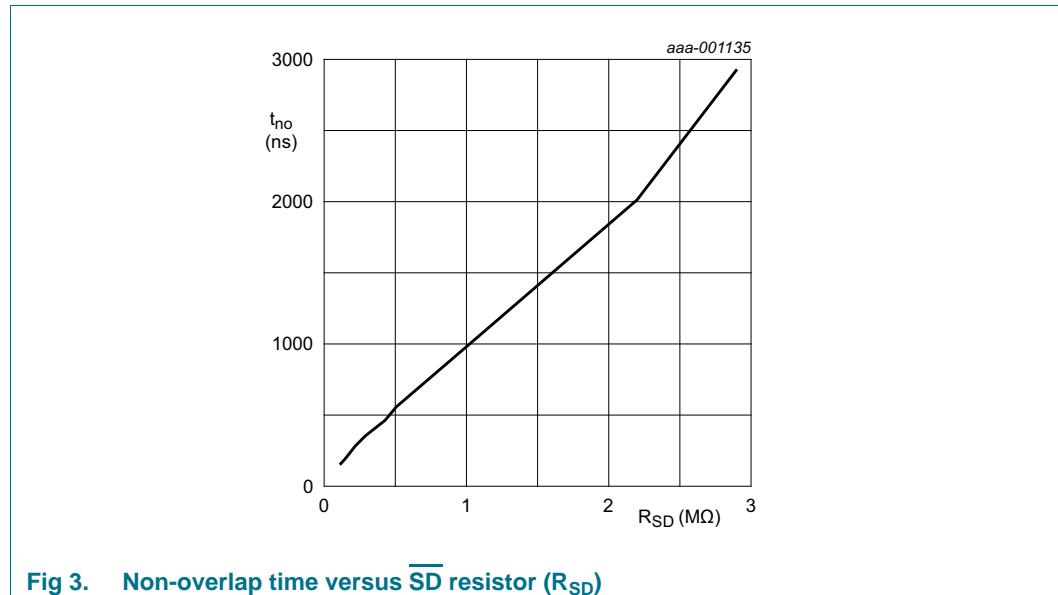


Fig 3. Non-overlap time versus \overline{SD} resistor (R_{SD})

7.4 NWP2081T shutdown protection

When the voltage at pin \overline{SD} is pulled below V_{IH} , the internal sink drivers of the pins GL and GH are immediately enabled to switch off the external power MOSFETs.

The shutdown comparator has a hysteresis of $V_{hys(SD)}$ to avoid multiple switching.

Preferably, pin \overline{SD} is pulled low via a collector of a transistor (see [Figure 4](#)) to avoid loading of this pin (Influences the non-overlap time settings) at normal operation.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DD}	supply voltage	nominal	0	15.5	V
V _{FS}	voltage on pin FS		V _{SH}	V _{SH} + 15.5	V
V _{SH}	voltage on pin SH	source high-side MOSFET t < 1 µs	-3 -14	+600 +600	V
V _{CLK}	voltage on pin CLK	logic input for output drivers	0	15.5	V
V _{i(SD)}	input voltage on pin \overline{SD}	logic input for output drivers and analog input for non-overlap setting	0	15.5	V
SR	slew rate	on pin SH; repetitive	-6	+6	V/ns
T _j	junction temperature		-40	+150	°C
T _{amb}	ambient temperature		-40	+150	°C
T _{stg}	storage temperature		-55	+150	°C
V _{ESD}	electrostatic discharge voltage	human body model: pins FS, GH and SH pins V _{DD} , \overline{SD} , CLK, and GL charge device model: all pins	[1] - - [2] -	1 2 500	kV

[1] In accordance with the Human Body Model (HBM): equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

[2] In accordance with the Charged Device Model (CDM): equivalent to discharging the IC up to 1 kV and the subsequent discharging of each pin down to 0 V over a 1 Ω resistor.

9. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
SO8				
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] 160	K/W

[1] In accordance with IEC 60747-1.

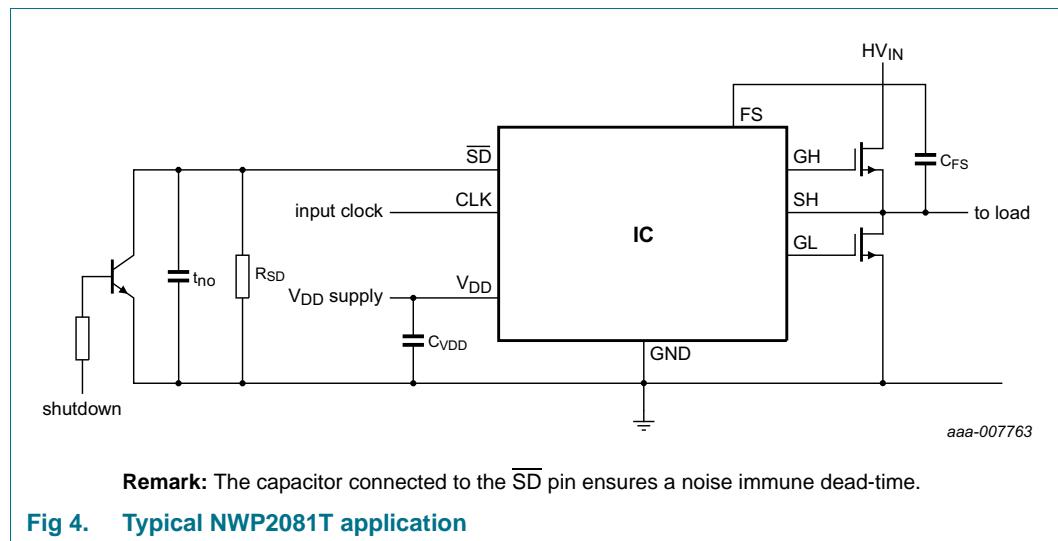
10. Characteristics

Table 6. Characteristics

$T_j = 25^\circ\text{C}$; all voltages are measured with respect to SGND; $V_{DD} = 12.8\text{ V}$; positive currents flow into the IC.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
High-voltage supply						
I_{leak}	leakage current	$V_{FS} = V_{GH} = V_{SH} = 600\text{ V}$	-	-	10	μA
Start-up state						
I_{VDD}	current on pin V_{DD}		420	520	620	μA
$V_{DD(\text{start})}$	start supply voltage		9	10	11	V
$V_{DD(\text{stop})}$	stop supply voltage		8	8.5	9	V
$V_{DD(\text{hys})}$	hysteresis of supply voltage	start-to-stop	1	1.5	2	V
Pin CLK input						
V_{IH}	HIGH-level input voltage		2.7	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.8	V
$I_{I(\text{CLK})}$	input current on pin CLK		-	0	1	μA
Pin SD input						
V_{IH}	HIGH-level input voltage	to activate shutdown	1.6	2.2	2.8	V
$V_{hys(\text{SD})}$	hysteresis voltage on pin \overline{SD}		-	400	-	mV
t_{no}	non-overlap time	$R_{SD} = 100\text{ k}\Omega$; typical minimum	-	140	-	ns
		$R_{SD} = 3\text{ M}\Omega$; typical maximum	-	2.4	-	μs
Gate drivers						
$I_{O(\text{source})}$	output source current	$V_{FS} = V_{VDD} = 12\text{ V}$; $V_{SH} = 0\text{ V}$; $V_{GH} = V_{GL} = 8\text{ V}$	-	200	-	mA
$I_{O(\text{sink})}$	output sink current	$V_{FS} = V_{VDD} = 12\text{ V}$; $V_{SH} = 0\text{ V}$; $V_{GH} = V_{GL} = 4\text{ V}$	-	400	-	mA
$V_{d(\text{bs})}$	bootstrap diode voltage	$I_{d(\text{bs})} = 20\text{ mA}$	-	2.3	-	V
V_{UVLO}	undervoltage lockout voltage	reset	3.6	4.2	4.8	V
I_{FS}	current on pin FS	$V_{FS} = V_{VDD} = 12\text{ V}$; $V_{SH} = 0\text{ V}$	27	32	37	μA
f_{max}	maximum frequency		800	-	-	kHz

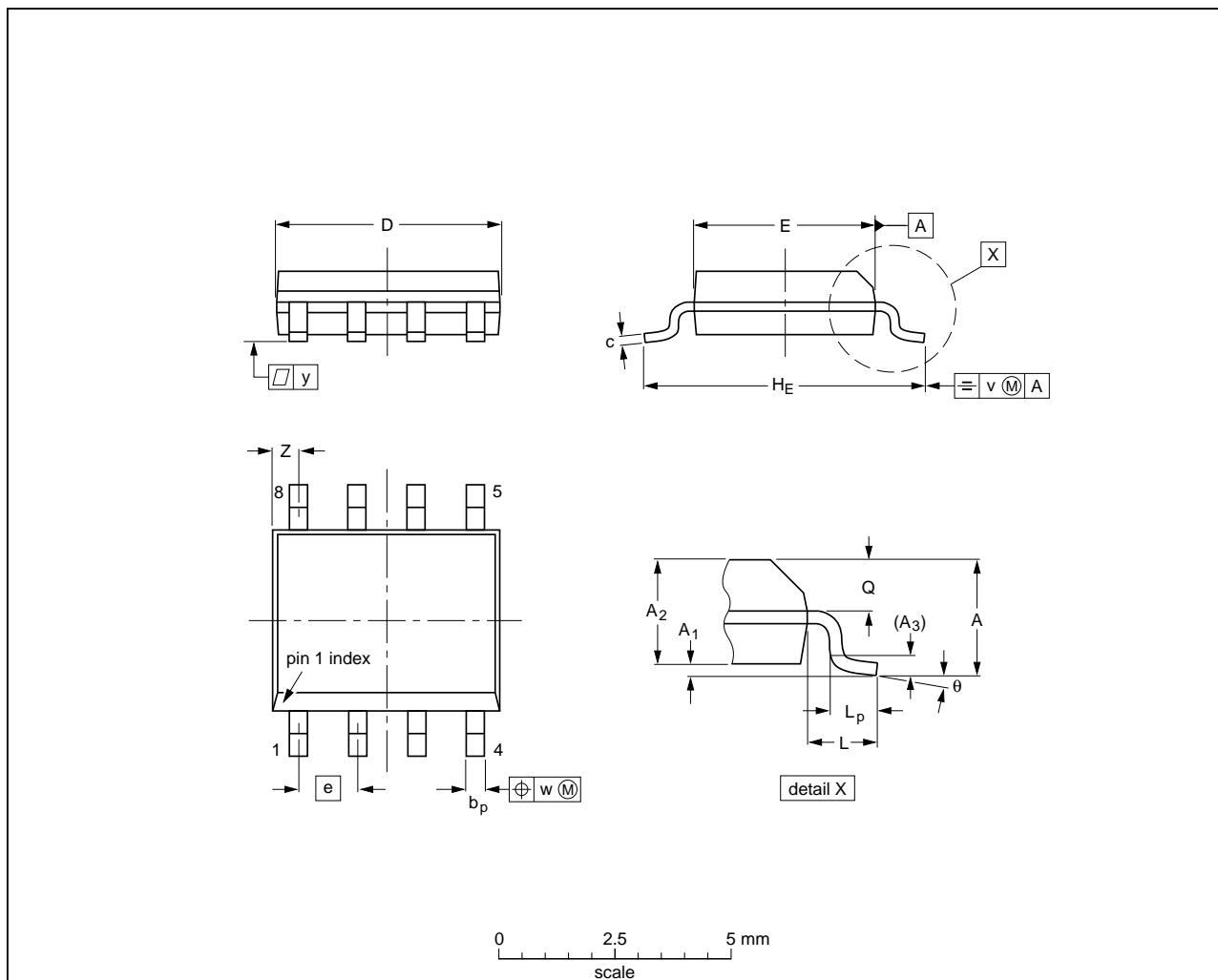
11. Application information



12. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.20	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Notes

- Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
- Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT96-1	076E03	MS-012			99-12-27 03-02-18

Fig 5. Package outline SOT96-1 (SO8)

13. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NWP2081T v.1	20130903	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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